

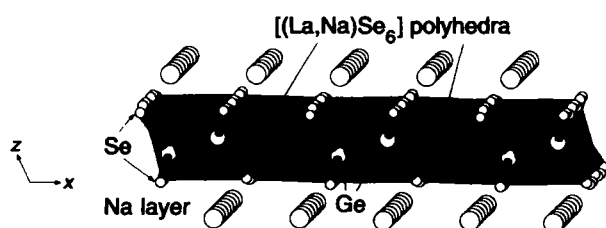
Crystal structure of nonasodium lanthanum(III) bis[hexaselenodigermanate], Na₉La[Ge₂Se₆]₂

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Received April 15, 2005; accepted and available on-line May 31, 2005; CSD no. 409826



Abstract

Ge₄LaNa₉Se₁₂, monoclinic, C12/m1 (no. 12), $a = 7.974(1) \text{ \AA}$, $b = 12.337(2) \text{ \AA}$, $c = 7.114(1) \text{ \AA}$, $\beta = 107.101(3)^\circ$, $V = 669.0 \text{ \AA}^3$, $Z = 1$, $R_{\text{gt}}(F) = 0.027$, $wR_{\text{ref}}(F^2) = 0.053$, $T = 173 \text{ K}$.

Source of material

Crystals of Na₉La[Ge₂Se₆]₂ were formed from a molten chalcogenide flux reaction of 19.2 mg La, 39.5 mg Ge, 110.2 mg Se, and 57.2 mg Na₂Se₂. These reactants were combined, loaded into a carbon crucible and then placed in a fused silica ampoule in an inert atmosphere glovebox. The ampoule was sealed under vacuum and heated to 725 °C at a rate of 35 K/h. After 150 hours of heating, the ampoule was cooled at 4 K/h to RT. Platy crystals were obtained after the product was washed with dimethylformamide to dissolve any remaining flux.

Experimental details

The structure of Na₉La[Ge₂Se₆]₂ was modeled with occupational disorder at the La1/Na1 site. When the atoms were allowed to refine freely, the occupancies of La1 and Na1 gave 0.246(2)/0.754, yielding a charge balanced structure of 0.25/0.75.

Table 2. Atomic coordinates and displacement parameters (in Å²).

Atom	Site	Occ.	x	y	z	U ₁₁	U ₂₂	U ₃₃	U ₁₂	U ₁₃	U ₂₃
La(1)	4h	0.25	½	0.67785(7)	½	0.0199(6)	0.0203(4)	0.0217(5)	0	0.0076(5)	0
Na(1)	4h	0.75	½	0.67785	½	0.0199	0.0203	0.0217	0	0.0076	0
Na(2)	4g	0	0	0.6543(2)	0	0.038(2)	0.039(2)	0.040(2)	0	0.020(2)	0
Na(3)	2a	½	½	½	0	0.031(2)	0.035(2)	0.035(2)	0	−0.003(2)	0
Ge(1)	4i	0.15881(8)	½	0.55861(9)	0.0128(3)	0.0179(3)	0.0133(3)	0	0.0035(3)	0	0
Se(1)	8j	0.24966(6)	0.34334(3)	0.75270(6)	0.0218(3)	0.0171(2)	0.0190(2)	0.0017(2)	0.0051(2)	0.0033(2)	0.0033(2)
Se(2)	4i	0.25655(8)	½	0.27763(9)	0.0207(4)	0.0265(3)	0.0157(3)	0	0.0083(3)	0	0

Acknowledgment. This research was funded by NSF-DMR-0343412.

References

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Discussion

Na₉La[Ge₂Se₆]₂ belongs to a family of compounds with the general formula Na_{12−m}Ln^{m+}[M₂Q₆]₂ (M = Si or Ge; Q = Se or Te). The title compound is isostructural to the previously reported quaternary samarium compound, Na₉Sm[Ge₂Se₆]₂, but is not isostructural to the contemporary reported quaternary europium compound Na₈Eu₂[Si₂Se₆]₂ [1]. The structure contains ethane-like hexaselenodigermanate(III) anions, [Ge₂Se₆]^{6−}, and La1 is coordinated in a distorted octahedral fashion to six selenium atoms from three different [Ge₂Se₆]^{6−} anions. Na₉La[Ge₂Se₆]₂ is a two-dimensional structure with ∞{(La,Na₃)[Ge₂Se₆]^{6−}} layers separated by sodium cations. In this structure the Ge–Ge bond in [Ge₂Se₆]^{6−} has an angle of 19.2° relative to the layer plane; whereas in the similar compound Na₈Eu₂[Si₂Se₆]₂ [1], the Si–Si bond is in a perpendicular orientation with respect to the layers.

Table 1. Data collection and handling.

Crystal:	orange plate, size 0.05 × 0.40 × 0.40 mm
Wavelength:	Mo K _α radiation (0.71073 Å)
μ:	157.58 cm ^{−1}
Diffractometer, scan mode:	Bruker AXS SMART CCD, φ/ω
2θ _{max} :	46.42°
N(hkl) _{measured} , N(hkl) _{unique} :	2025, 960
Criterion for I _{obs} , N(hkl) _{gt} :	I _{obs} > 2 σ(I _{obs}), 914
N(param) _{refined} :	65
Programs:	SHELXS-97 [3], SHELXL-97 [4], X-Seed-A [5]